

# FGW30N120HD

**Discrete IGBT** 

## Discrete IGBT (High-Speed V series) 1200V / 30A

#### Features

Low power loss Low switching surge and noise High reliability, high ruggedness (RBSOA, SCSOA etc.)

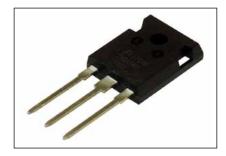
#### Applications

Uninterruptible power supply Power coditionner Power factor correction circuit

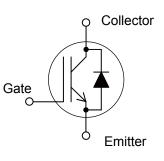
#### Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at T₀=25°C unless otherwise specified)

Items	Symbols	Characteristics	Units	Remarks			
Collector-Emitter Voltage	VCES	1200	V				
Gate-Emitter Voltage	VGES	±20	V				
DC Collector Current	LC@25	53	Α	Tc=25°C,Tj=150°C			
	LC@100	30	Α	Tc=100°C,Tj=150°C			
Pulsed Collector Current	ICP	90	Α	Note *1			
Turn-Off Safe Operating Area	-	90	Α	Vce≤1200V,Tj≤175°C			
Diode Forward Current	IF@25	36	Α				
	F@100	20	Α				
Diode Pulsed Current	IFP	90	Α	Note *1			
Short Circuit Withstand Time	tsc	5	μs	Vcc≤600V,VgE=12V Ti≤150°C			
IGBT Max. Power Dissipation	PD_IGBT	260		Tc=25°C			
FWD Max. Power Dissipation	PD_FWD	125	W	Tc=25°C			
<b>Operating Junction Temperature</b>	Tj	-40 ~ +175	°C				
Storage Temperature	Tstg	-55 ~ +175	°C				



#### Equivalent circuit



Note \*1 : Pulse width limited by Tjmax.

#### • Electrical characteristics (at T<sub>i</sub>= 25°C unless otherwise specified)

Items	Symbolo	Symbols Conditions		Characteristics			
	Symbols	conulions	min.	typ.	max.	Units	
Collector-Emitter Breakdown Voltage	V <sub>(BR)CES</sub>	Ic = 50μA, Vge = 0V	1200	-	-	V	
Zero Gate Voltage Collector Current	nt Ices Vce =	$V_{GE} = 1200V, V_{GE} = 0V$ $T_{j}=25^{\circ}C$	-	-	250	μA	
	ICES	, Ij=1/5°C	-	-	2	mA	
Gate-Emitter Leakage Current	IGES	$V_{CE} = 0V, V_{GE} = \pm 20V$	-	-	200	nA	
Gate-Emitter Threshold Voltage	V <sub>GE (th)</sub>	Vce = +20V, Ic = 30mA	4.0	5.0	6.0	V	
Collector-Emitter Saturation Voltage	VCE (sat)	$V_{GE} = +15V, I_{C} = 30A$ $\frac{T_{j}=25^{\circ}C}{T_{i}=175^{\circ}C}$	-	1.8 2.3	2.34	v	
Input Capacitance	Cies	V <sub>CE</sub> =25V	-	2350	-		
Output Capacitance	Coes	V <sub>GE</sub> =0V	-	105	-	pF	
Reverse Transfer Capacitance	Cres	f=1MHz	-	80	-		
Gate Charge	QG	V <sub>cc</sub> = 600V I <sub>c</sub> = 30A V <sub>GE</sub> = 15V	-	230	-	nC	
Turn-On Delay Time	t <sub>d(on)</sub>	T <sub>j</sub> = 25°C	-	28	-		
Rise Time	t	Vcc = 600V	-	28	-	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	Ic = 30A	-	260	-		
Fall Time	tr	V <sub>GE</sub> = 15V	-	38	-		
Turn-On Energy	Eon	$R_G = 10\Omega$	-	1.6	-		
Turn-Off Energy	Eoff	L = 500µH Energy loss include "tail" and FWD reverse recovery.	-	1.5	-	mJ	
Turn-On Delay Time	t <sub>d(on)</sub>	T <sub>j</sub> = 175°C	-	30	-	-	
Rise Time	t	V <sub>cc</sub> = 600V	-	30	-	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	Ic = 30A	-	300	-		
Fall Time	tr	V <sub>GE</sub> = 15V	-	65	-		
Turn-On Energy	Eon	$R_G = 10\Omega$	-	2.8	-		
Turn-Off Energy	Eoff	L = 500µH Energy loss include "tail" and FWD reverse recovery.	-	2.5	-	mJ	

#### • FWD Characteristics

Description	Symbol	Conditions	Conditions		Characteristics		
Description	Symbol	Conditions			typ.	max.	Unit
Forward Voltage Drop	VF	I⊧=20A	Tj=25°C	-	2.2	2.8	V
	VF	I⊧=20A	Tj=175°C	-	1.8	-	V
Diode Reverse Recovery Time	tm	Vcc=30V,I⊧ = 2.0A -di/dt=200A/µs		-	42	55	ns
Diode Reverse Recovery Time	trr2	Vcc=600V I⊧=20A			0.38	-	μs
Diode Reverse Recovery Charge	Qrr	-di⊧/dt=200A/µs Tj=25°C		-	0.95	-	μC
Diode Reverse Recovery Time	trr2	Vcc=600V I⊧=20A		-	0.66	-	μs
Diode Reverse Recovery Charge	Qrr	-di⊧/dt=200A/µs Tj=175°C		-	4.5	-	μC

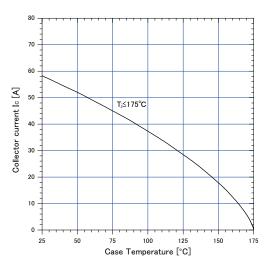
#### Thermal resistance characteristics

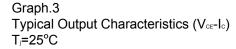
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	Units
Thermal Resistance, Junction-Ambient	Rth(j-a)	-	-	-	50	
Thermal Resistance, IGBT Junction to Case	Rth(j-c)_IGBT	-	-	-	0.568	°C/W
Thermal Resistance, FWD Junction to Case	Rth(j-c)_FWD	-	-	-	1.191	

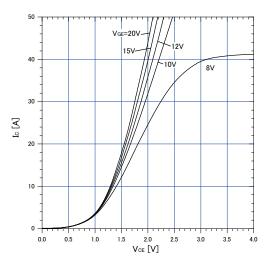
#### Characteristics (Representative)

Graph.1

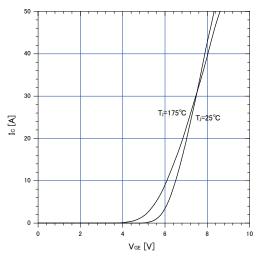
DC Collector Current vs  $T_c$  $V_{GE} \ge +15V$ ,  $T_i \le 175^{\circ}C$ 

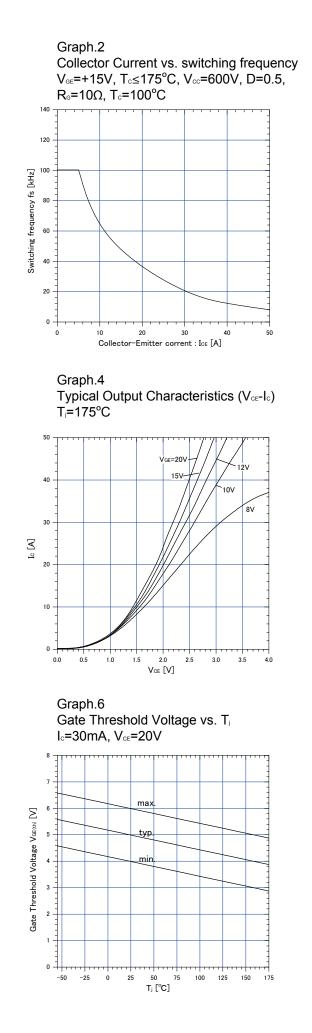


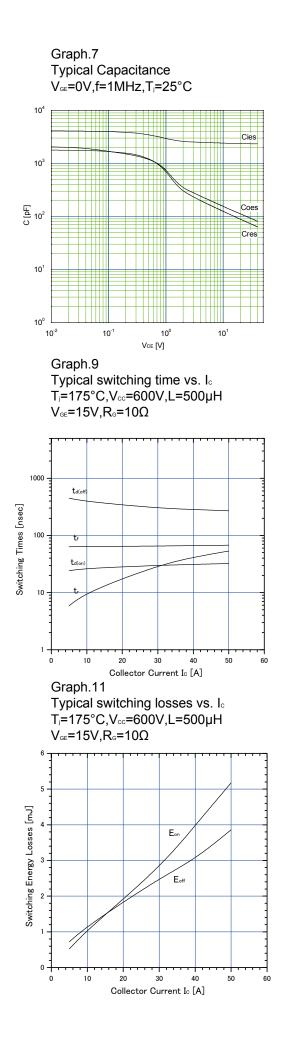


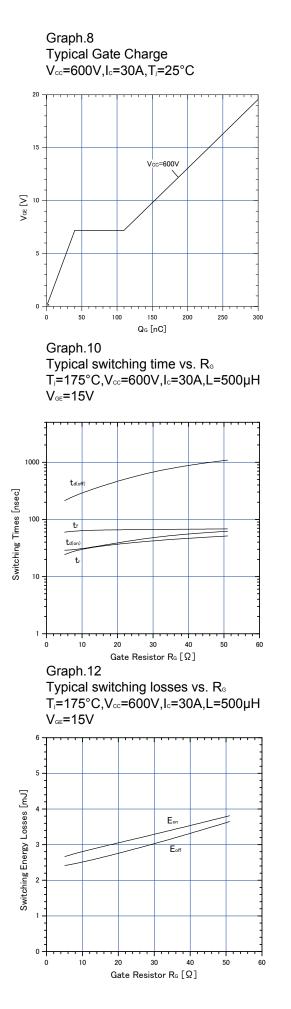


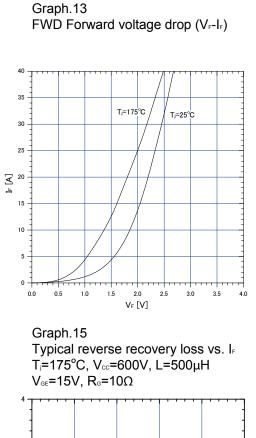


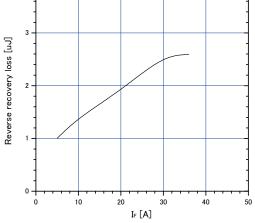


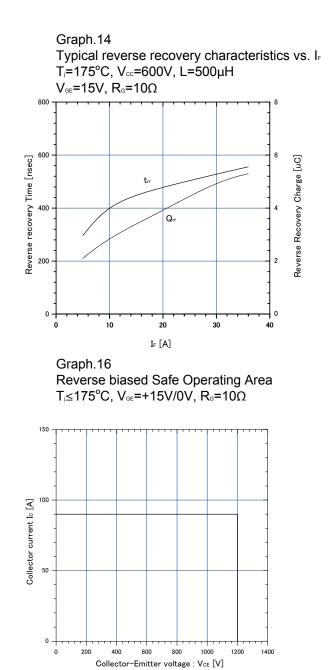




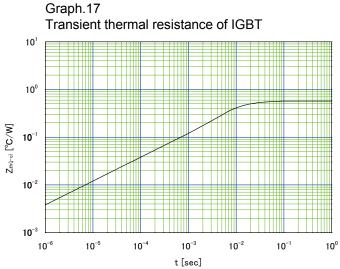


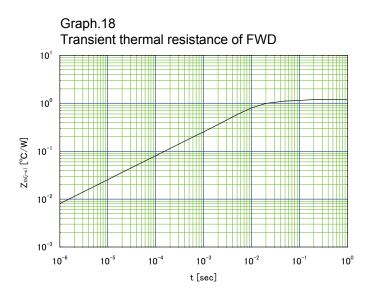






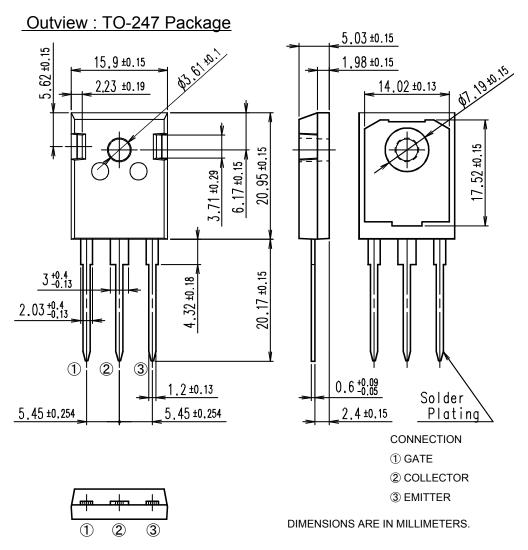
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### Outline Drawings, mm



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